74LV4052

Dual 4-channel analog multiplexer/demultiplexer Rev. 4 — 1 July 2013 Pro

Product data sheet

General description 1.

The 74LV4052 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4052.

The 74LV4052 is a dual 4-channel analog multiplexer/demultiplexer with a common select logic. Each multiplexer has four independent inputs/outputs (nY0 to nY3) and a common input/output (nZ). The common channel select logics include two digital select inputs (S0 and S1) and an active LOW enable input (\overline{E}) . With \overline{E} LOW, one of the four switches is selected (low impedance ON-state) by S0 and S1. With E HIGH, all switches are in the high impedance OFF-state, independent of S0 and S1. V_{CC} and GND are the supply voltage pins for the digital control inputs (S0, S1 and E). The V_{CC} to GND ranges are 1.0 V to 6.0 V. The analog inputs/outputs (nY0, to nY3, and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. V_{CC} - V_{EE} may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

Features and benefits 2.

- Optimized for low-voltage applications: 1.0 V to 6.0 V
- Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- Low ON resistance:
 - ♦ 145 Ω (typical) at $V_{CC} V_{EE} = 2.0 \text{ V}$
 - 90 Ω (typical) at V_{CC} − V_{EE} = 3.0 V
 - 60 Ω (typical) at $V_{CC} V_{EE} = 4.5 \text{ V}$
- Logic level translation:
 - ◆ To enable 3 V logic to communicate with ± 3 V analog signals
- Typical 'break before make' built in
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



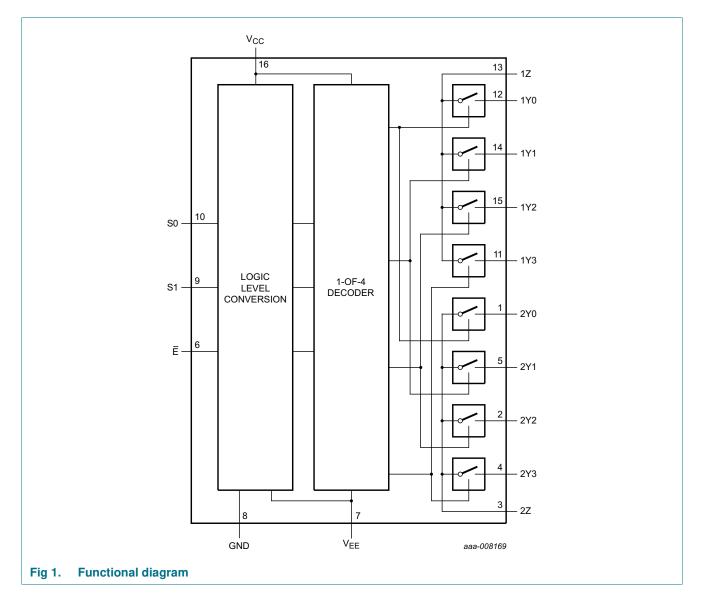
Dual 4-channel analog multiplexer/demultiplexer

3. Ordering information

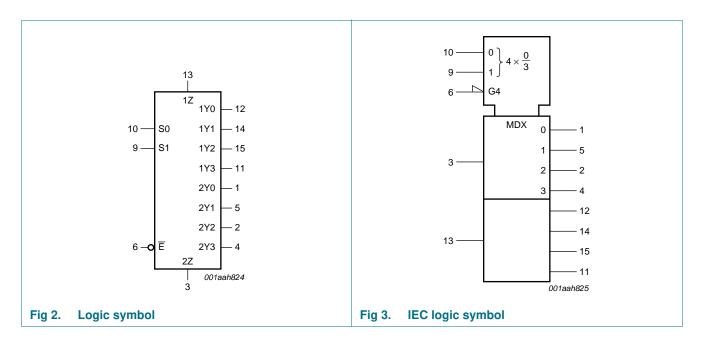
Table 1. Ordering information

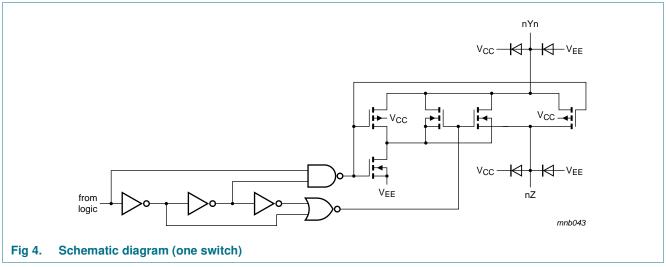
Type number	Package								
	Temperature range	Name	Description	Version					
74LV4052N	−40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
74LV4052D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
74LV4052DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
74LV4052PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					

4. Functional diagram



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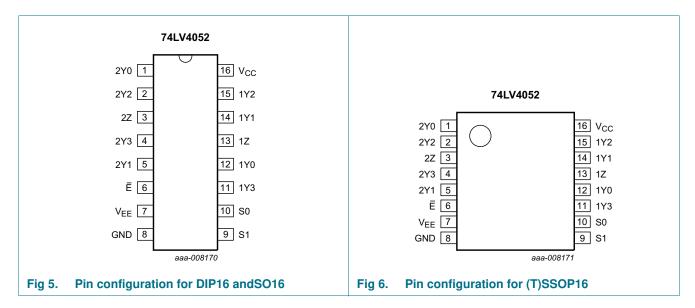




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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
2Y0	1	independent input or output
2Y2	2	independent input or output
2Z	3	common input or output
2Y3	4	independent input or output
2Y1	5	independent input or output
Ē	6	enable input (active LOW)
V _{EE}	7	negative supply voltage
GND	8	ground (0 V)
S1	9	select logic input
S0	10	select logic input
1Y3	11	independent input or output
1Y0	12	independent input or output
1Z	13	common input or output
1Y1	14	independent input or output
1Y2	15	independent input or output
V _{CC}	16	positive supply voltage

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6. Functional description

Table 3. Function table[1]

Input			Channel on
Ē	S1	S0	
L	L	L	nY0 and nZ
L	L	Н	nY1 and nZ
L	Н	L	nY2 and nZ
L	Н	Н	nY3 and nZ
Н	Χ	Χ	none

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{\rm SS}$ = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		<u>[1]</u> –0.5	+7.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	[2] -	±20	mA
I _{SK}	switch clamping current	$V_{SW} < -0.5 \ V$ or $V_{SW} > V_{CC} + 0.5 \ V$	[2] -	±20	mA
I_{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	[2] -	±25	mA
T _{stg}	storage temperature		–65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3]		
		DIP16 package	-	750	mW
		SO16 package	-	500	mW
		SSOP16 and TSSOP16 package	-	400	mW

^[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current flows out of terminals nYn. In this case, there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

^[2] The minimum input voltage rating may be exceeded if the input current rating is observed.

^[3] For DIP16 package: above 70 °C the value of P_{tot} derates linearly with 12 mW/K.
For SO16 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.
For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

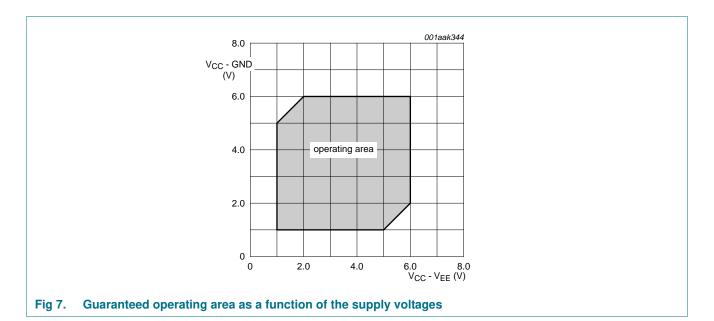
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8. Recommended operating conditions

Table 5. Recommended operating conditions[1]

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage	see Figure 7	1	3.3	6	V
V _I	input voltage		0	-	V_{CC}	V
V_{SW}	switch voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	-	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	-	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 6.0 \text{ V}$	-	-	100	ns/V

^[1] The static characteristics are guaranteed from V_{CC} = 1.2 V to 6.0 V. However, LV devices are guaranteed to function down to V_{CC} = 1.0 V (with input levels GND or V_{CC}).



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9. Static characteristics

Table 6. Static characteristics

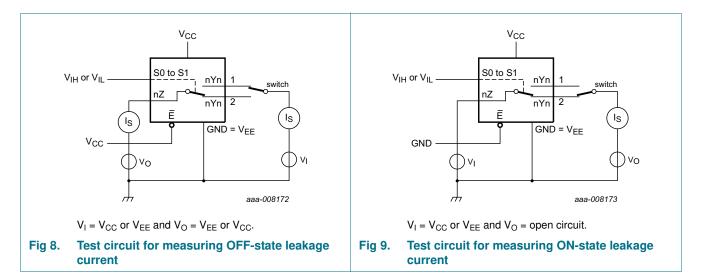
At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
		$V_{CC} = 2.0 \text{ V}$	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		$V_{CC} = 4.5 \text{ V}$	3.15	-	-	3.15	-	V
		$V_{CC} = 6.0 \text{ V}$	4.20	-	-	4.20	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
		$V_{CC} = 2.0 \text{ V}$	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	8.0	-	0.8	V
		$V_{CC} = 4.5 \text{ V}$	-	-	1.35	-	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	-	1.80	-	1.80	V
I	input leakage current	$V_I = V_{CC}$ or GND						
		$V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μΑ
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	2.0	μА
$I_{S(OFF)}$	OFF-state leakage current	$V_I = V_{IH}$ or V_{IL} ; see <u>Figure 8</u>						
		$V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μΑ
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	2.0	μΑ
$I_{S(ON)}$	ON-state leakage current	$V_I = V_{IH}$ or V_{IL} ; see <u>Figure 9</u>						
		$V_{CC} = 3.6 \text{ V}$	-	-	1.0	-	1.0	μА
		$V_{CC} = 6.0 \text{ V}$	-	-	2.0	-	2.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A						
		$V_{CC} = 3.6 \text{ V}$	-	-	20	-	40	μА
		$V_{CC} = 6.0 \text{ V}$	-	-	40	-	80	μА
ΔI_{CC}	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
Cı	input capacitance		-	3.5	-	-	-	pF
C_{sw}	switch capacitance	independent pins nYn	-	5	-	-	-	pF
		common pins nZ	-	12	-	-	-	pF

^[1] Typical values are measured at T_{amb} = 25 °C.

Dual 4-channel analog multiplexer/demultiplexer

9.1 Test circuits



9.2 ON resistance

Table 7. ON resistanceAt recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and Figure 11.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = 0 V \text{ to } V_{CC} - V_{EE}$			•				
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μA		-	145	325	-	375	Ω
		V_{CC} = 2.7 V; I_{SW} = 1000 μA		-	90	200	-	235	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	80	180	-	210	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	60	135	-	160	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	55	125	-	145	Ω
ΔR_{ON}	ON resistance mismatch	$V_I = 0 V \text{ to } V_{CC} - V_{EE}$							
	between channels	$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	2]	-	-	-	-	-	Ω
		V_{CC} = 2.0 V; I_{SW} = 1000 μA		-	5	-	-	-	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	4	-	-	-	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$		-	4	-	-	-	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	3	-	-	-	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$		-	2	-	-	-	Ω

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Table 7. ON resistance ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 10</u> and Figure 11.

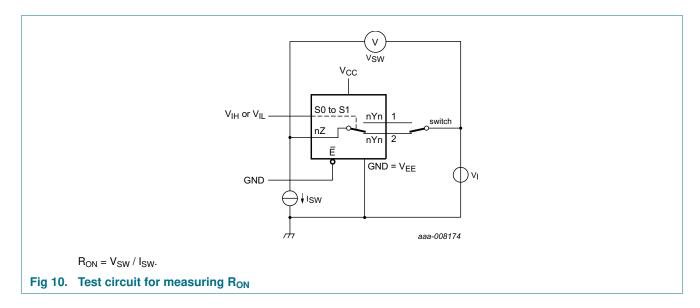
Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
R _{ON(rail)}	ON resistance (rail)	$V_I = GND$					'	
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$	-	225	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	110	235	-	270	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	70	145	-	165	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$	-	60	130	-	150	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	45	100	-	115	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	40	85	-	100	Ω
R _{ON(rail)}	ON resistance (rail)	$V_{I} = V_{CC} - V_{EE}$						
		$V_{CC} = 1.2 \text{ V}; I_{SW} = 100 \mu\text{A}$ [2]	-	250	-	-	-	Ω
		$V_{CC} = 2.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	120	320	-	370	Ω
		$V_{CC} = 2.7 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	75	195	-	225	Ω
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V};$ $I_{SW} = 1000 \mu\text{A}$	-	70	175	-	205	Ω
		$V_{CC} = 4.5 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	50	130	-	150	Ω
		$V_{CC} = 6.0 \text{ V}; I_{SW} = 1000 \mu\text{A}$	-	45	120	-	135	Ω

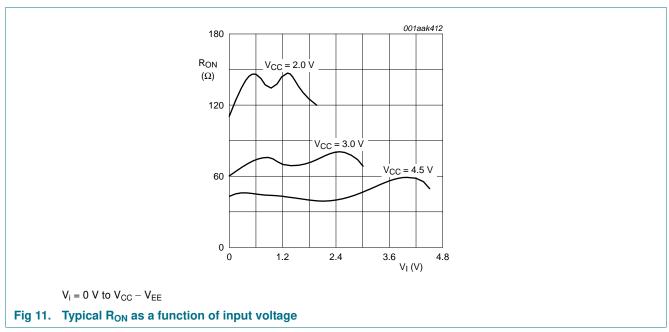
^[1] Typical values are measured at T_{amb} = 25 °C.

^[2] When supply voltages ($V_{CC} - V_{EE}$) near 1.2 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 1.2 V, only use these devices for transmitting digital signals.

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9.3 On resistance waveform and test circuit





Dual 4-channel analog multiplexer/demultiplexer

10. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Figure 14.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	–40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	nYn to nZ, nZ to nYn; see Figure 12	[2]			'			'
		V _{CC} = 1.2 V		-	25	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	9	17	-	20	ns
		V _{CC} = 2.7 V		-	6	13	-	15	ns
		V _{CC} = 3.0 V to 3.6 V	[3]	-	5	10	-	12	ns
		V _{CC} = 4.5 V		-	4	9	-	10	ns
		V _{CC} = 6.0 V		-	3	7	-	8	ns
t _{en}	enable time	E, Sn to nYn, nZ; see Figure 13	[2]						
		V _{CC} = 1.2 V		-	190	-	-	-	ns
		V _{CC} = 2.0 V		-	65	121	-	146	ns
		V _{CC} = 2.7 V		-	48	89	-	108	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 15 \text{ pF}$	[3]	-	30	-	-	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	36	71	-	86	ns
		V _{CC} = 4.5 V		-	32	60	-	73	ns
		V _{CC} = 6.0 V		-	25	46	-	56	ns
t _{dis}	disable time	E, Sn to nYn, nZ; see Figure 13	[2]						
		V _{CC} = 1.2 V		-	125	-	-	-	ns
		V _{CC} = 2.0 V		-	43	80	-	95	ns
		V _{CC} = 2.7 V		-	33	59	-	71	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$	[3]	-	22	-	-	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	26	48	-	57	ns
		V _{CC} = 4.5 V		-	23	41	-	49	ns
		$V_{CC} = 6.0 \text{ V}$		-	18	32	-	38	ns
C_{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[4]	-	57	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .

 t_{en} is the same as t_{PZL} and t_{PZH} .

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

- [3] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V).
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma ((C_L + C_{sw}) \times V_{CC}{}^2 \times f_o) \text{ where:}$

 f_i = input frequency in MHz, f_o = output frequency in MHz

 C_L = output load capacitance in pF

 C_{sw} = maximum switch capacitance in pF;

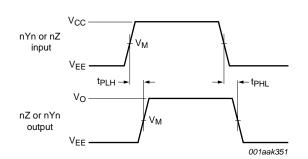
V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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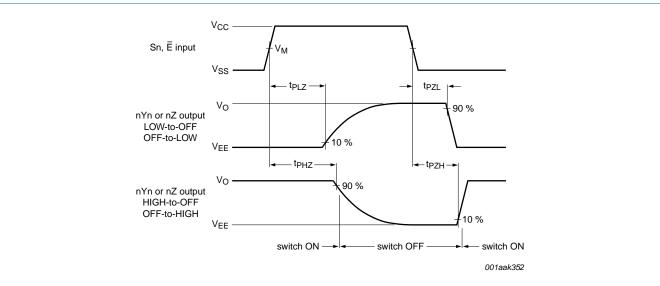
10.1 Waveforms



Measurement points are given in Table 9.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output levels that occur with the output load.

Fig 12. nYn, nZ to nZ, nYn propagation delays



Measurement points are given in Table 9.

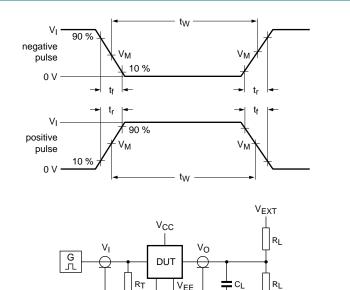
 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical voltage output levels that occur with the output load.

Fig 13. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
< 2.7 V	0.5V _{CC}	0.5V _{CC}
2.7 V to 3.6 V	1.5 V	1.5 V
> 3.6 V	0.5V _{CC}	0.5V _{CC}

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Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 14. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V _{EXT}		
V _{CC}	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t_{PZL}, t_{PLZ}
< 2.7 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	2V _{CC}
2.7 V to 3.6 V	2.7 V	≤ 6 ns	15 pF, 50 pF	1 kΩ	open	V_{EE}	2V _{CC}
> 3.6 V	V _{CC}	≤ 6 ns	50 pF	1 kΩ	open	V_{EE}	2V _{CC}

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10.2 Additional dynamic parameters

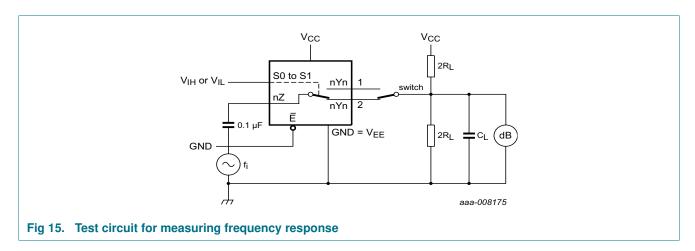
Table 11. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); t_r = $t_f \le 6.0$ ns; T_{amb} = 25 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic	f_i = 1 kHz; C_L = 50 pF; R_L = 10 k Ω ; see <u>Figure 19</u>				
	distortion	$V_{CC} = 3.0 \text{ V}; V_I = 2.75 \text{ V (p-p)}$	-	8.0	-	%
		$V_{CC} = 6.0 \text{ V}; V_I = 5.5 \text{ V (p-p)}$	-	0.4	-	%
		f_i = 10 kHz; C_L = 50 pF; R_L = 10 k Ω ; see <u>Figure 19</u>				
		$V_{CC} = 3.0 \text{ V}; V_I = 2.75 \text{ V (p-p)}$	-	2.4	-	%
		$V_{CC} = 6.0 \text{ V}; V_I = 5.5 \text{ V (p-p)}$	-	1.2	-	%
f _(-3dB)	–3 dB frequency	$C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 15	[1]			
	response	V _{CC} = 3.0 V	-	180	-	MHz
		$V_{CC} = 6.0 \text{ V}$	-	200	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω ; see Figure 17	[2]			
		V _{CC} = 3.0 V	-	-50	-	dB
		V _{CC} = 6.0 V	-	-50	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1$ MHz; $C_L = 50$ pF; $R_L = 600$ Ω ; see Figure 20				
		V _{CC} = 3.0 V	-	0.11	-	V
		$V_{CC} = 6.0 \text{ V}$	-	0.12	-	V
Xtalk	crosstalk	between switches; f_i = 1 MHz; C_L = 50 pF; R_L = 600 Ω ; see Figure 21	[2]			
		V _{CC} = 3.0 V	-	-60	-	dB
		V _{CC} = 6.0 V	-	-60	-	dB

^[1] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 50 Ω), adjust f_i voltage.

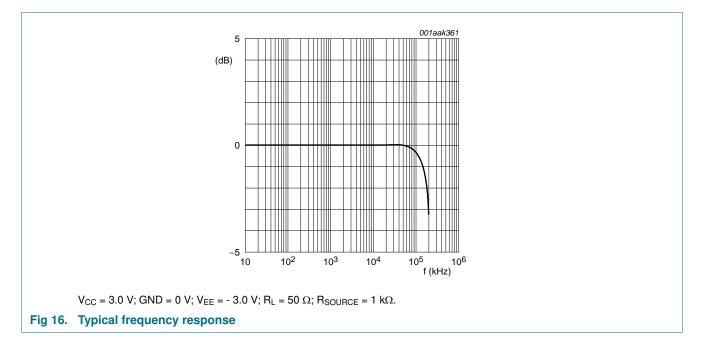
10.2.1 Test circuits

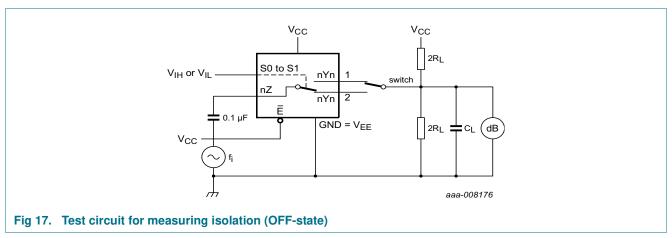


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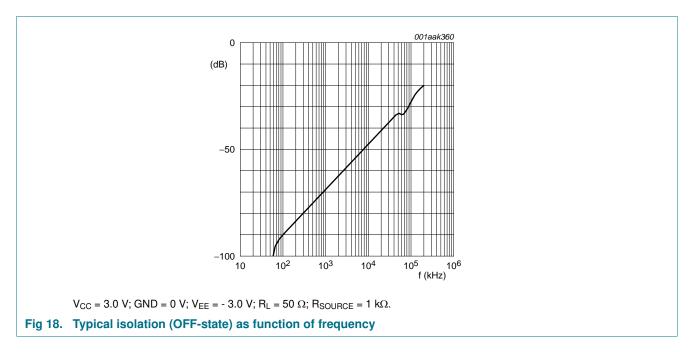
^[2] To obtain 0 dBm level at output for 1 MHz (0 dBm = 1 mW into 600 Ω), adjust f_i voltage.

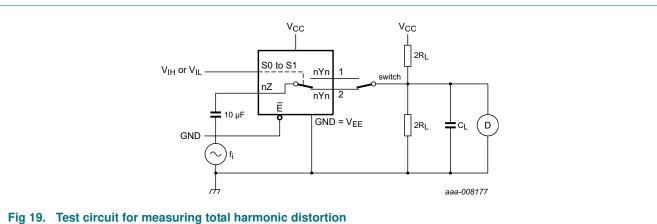
Dual 4-channel analog multiplexer/demultiplexer



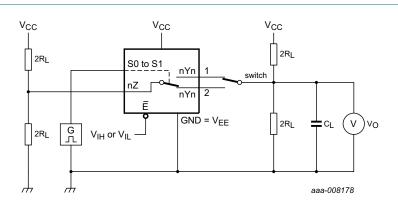


Dual 4-channel analog multiplexer/demultiplexer

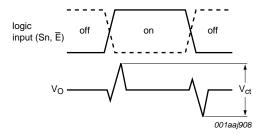




Dual 4-channel analog multiplexer/demultiplexer



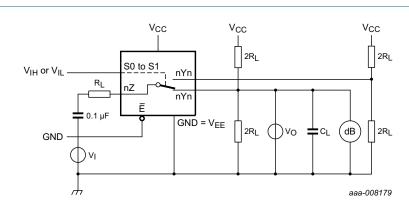
a. Test circuit



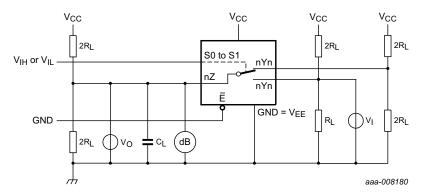
b. Input and output pulse definitions V_I may be connected to Sn or \overline{E} .

Fig 20. Test circuit for measuring crosstalk voltage between digital inputs and switch

Dual 4-channel analog multiplexer/demultiplexer



a. Switch on channel.



b. Switch off channel.

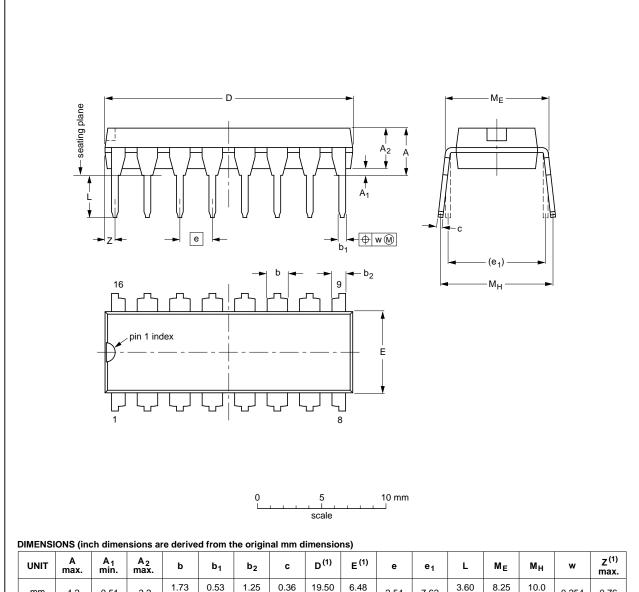
Fig 21. Test circuit for measuring crosstalk between switches

Dual 4-channel analog multiplexer/demultiplexer

11. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



ı	UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
	mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
ir	nches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	1350E DATE	
SOT38-4					95-01-14 03-02-13	

Fig 22. Package outline SOT38-4 (DIP16)

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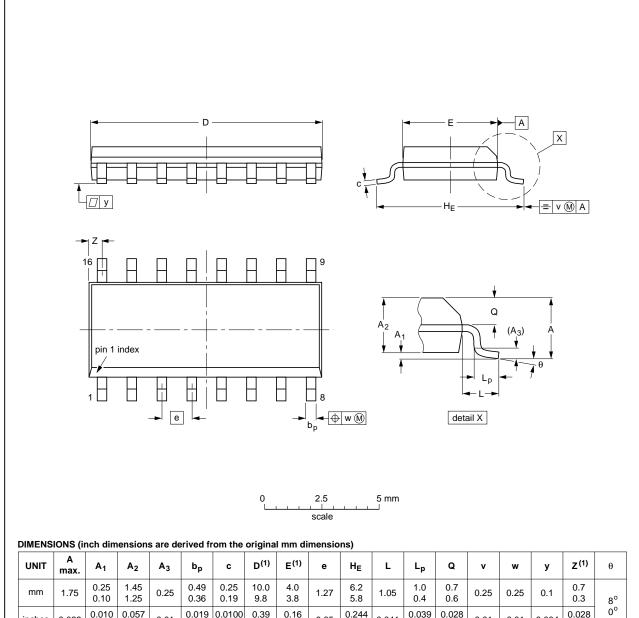
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74LV4052 **NXP Semiconductors**

Dual 4-channel analog multiplexer/demultiplexer

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	l	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ICCUIT DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig 23. Package outline SOT109-1 (SO16)

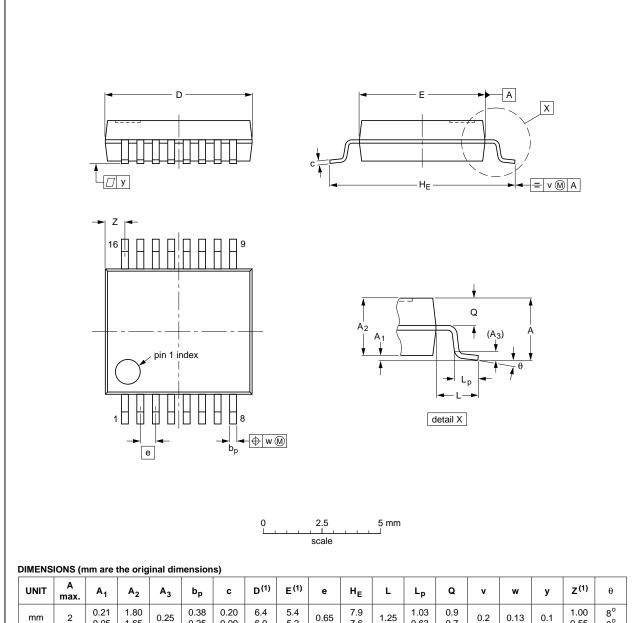
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74LV4052 **NXP Semiconductors**

Dual 4-channel analog multiplexer/demultiplexer

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT338-1		MO-150				99-12-27 03-02-19

Fig 24. Package outline SOT338-1 (SSOP16)

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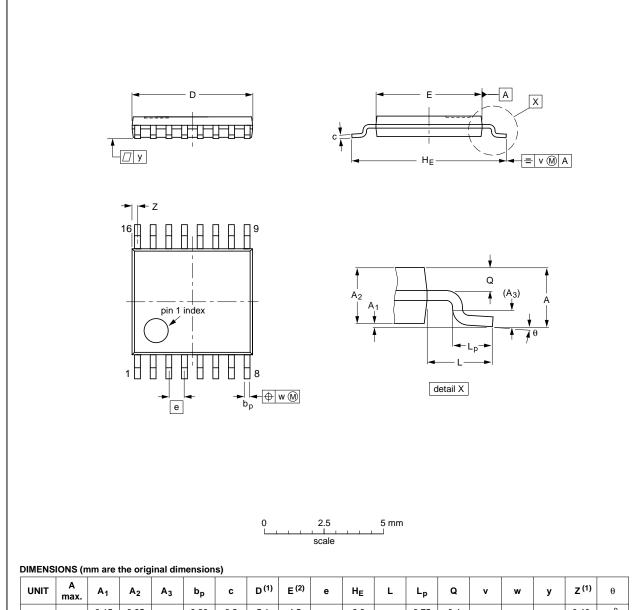
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74LV4052 **NXP Semiconductors**

Dual 4-channel analog multiplexer/demultiplexer

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNI	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT403-1		MO-153				-99-12-27 03-02-18	

Fig 25. Package outline SOT403-1 (TSSOP16)

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Dual 4-channel analog multiplexer/demultiplexer

12. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LV4052 v.4	20130701	Product data sheet	-	74LV4052 v.3
Modifications:	guidelines o	of this data sheet has been of NXP Semiconductors. have been adapted to the n		·
74LV4052 v.3	19980623	Product specification	-	74LV4052 v.2
74LV4052 v.2	19970715	Product specification	-	-

Dual 4-channel analog multiplexer/demultiplexer

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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